NSN 5962-01-123-0800

Memory Microcircuit - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5962-01-123-0800 **Body Length:** 0.400 inches **Body Width:** Between 0.245 inches and 0.305 inches **Body Height:** Between 0.045 inches and 0.085 inches **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **End Application:** F-16 81755 **Features Provided:** Hermetically sealed and bipolar and programmable and programmed and w/open collector **Inclosure Material:** Ceramic and glass **Inclosure Configuration:** Flat pack **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 10 input **Terminal Surface Treatment:** Solder **Voltage Rating And Type Per Characteristic:** 5.5 volts power source **Time Rating Per Chacteristic:** 75.00 nanoseconds propagation delay time, low to high level output and 75.00 nanoseconds propagation delay time, high to low level output **Memory Device Type:** Rom **Test Data Document:** 88818-a574a025 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 16 flat leads Shelf Life: N/a **Unit Of Measure:**

Fiig: A458a0

Demilitarization: Yes - demil/mli